General Purpose Transistors

PNP Silicon

Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V_{CEO}	-45	V
Collector – Base Voltage	V _{CBO}	-50	V
Emitter – Base Voltage	V _{EBO}	-5.0	V
Collector Current – Continuous	I _C	-500	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T _A = 25°C Derate above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction–to–Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

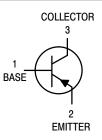
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.
- 2. Alumina = 0.4 x 0.3 x 0.024 in 99.5% alumina.



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SOT-23 CASE 318 STYLE 6

MARKING DIAGRAM



5xx = Device Code xx = A1, B1, or C $M = Date Code^*$

■ = Pb–Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted.)

Symbol	Min	Тур	Max	Unit
V _(BR) CEO	-45	_	_	V
V _(BR) CES	-50	-	-	V
V _{(BR)EBO}	-5.0	_	_	V
Ісво	_ _	_ _	-100 -5.0	nA μA
SBC807-25L	100 160 250 40	- - -	250 400 600 –	-
V _{CE(sat)}	-	-	-0.7	V
V _{BE(on)}	-	-	-1.2	V
	•	•	-	
f⊤	100	-	_	MHz
C _{obo}	-	10	-	pF
	V(BR)CEO V(BR)CES V(BR)EBO ICBO ICBO NFE VCE(sat) VBE(on)	V(BR)CEO -45 V(BR)CES -50 V(BR)EBO -5.0 ICBO	V(BR)CEO -45 - V(BR)CES -50 - V(BR)EBO -5.0 - ICBO ICBO SBC807-25L SBC807-40L 250 - VCE(sat) VBE(on) T 100 - T 100 -	V _{(BR)CEO}

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

Device	Specific Marking	Package	Shipping [†]	
BC807-16LT1G	504		0000 /Tara 0 Davi	
SBC807-16LT1G*	5A1		3000 / Tape & Reel	
BC807-16LT3G	5A1		40,000 / Tana & Daal	
SBC807-25LT1G*	5A1		10,000 / Tape & Reel	
BC807-25LT1G	5D4		2000 / Tono & Dool	
SBC807-25LT1G*	5B1	SOT-23	3000 / Tape & Reel	
BC807-25LT3G	5B1	(Pb-Free)	10,000 / Tape & Reel	
SBC807-25LT3G*	351			
BC807-40LT1G	5C		3000 / Tape & Reel	
SBC807-40LT1G*			3000 / Tape & Reel	
BC807-40LT3G	5C		10 000 / Tong & Rool	
SBC807-40LT3G*	50		10,000 / Tape & Reel	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging

Specifications Brochure, BRD8011/D.
*S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable.

TYPICAL CHARACTERISTICS - BC807-16LT1

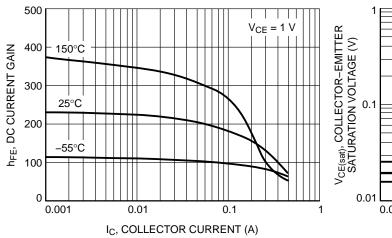


Figure 1. DC Current Gain vs. Collector Current

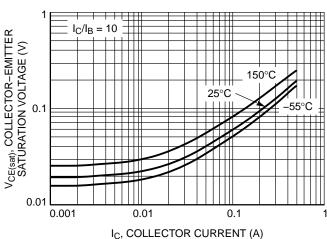


Figure 2. Collector Emitter Saturation Voltage vs. Collector Current

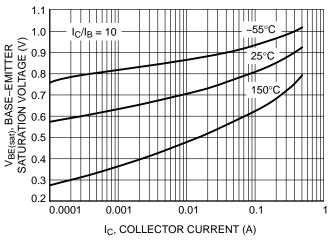


Figure 3. Base Emitter Saturation Voltage vs.
Collector Current

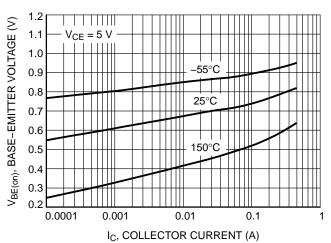


Figure 4. Base Emitter Voltage vs. Collector Current

TYPICAL CHARACTERISTICS - BC807-16LT1

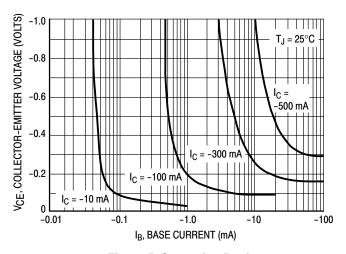


Figure 5. Saturation Region

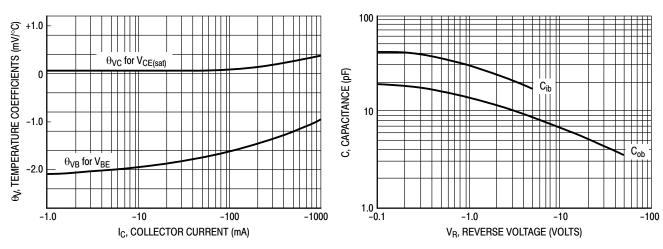


Figure 6. Temperature Coefficients

Figure 7. Capacitances

TYPICAL CHARACTERISTICS - BC807-25LT1

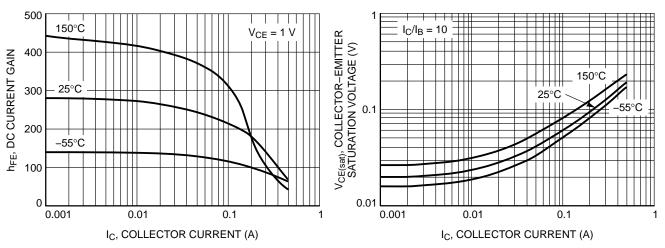


Figure 8. DC Current Gain vs. Collector Current

Figure 9. Collector Emitter Saturation Voltage vs. Collector Current

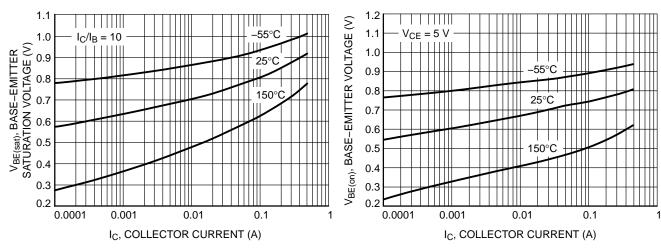


Figure 10. Base Emitter Saturation Voltage vs.
Collector Current

Figure 11. Base Emitter Voltage vs. Collector Current

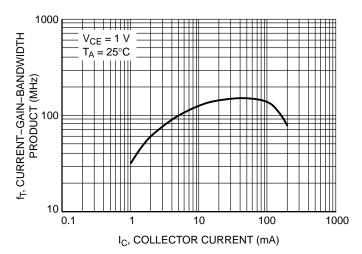


Figure 12. Current Gain Bandwidth Product vs. Collector Current

TYPICAL CHARACTERISTICS - BC807-25LT1

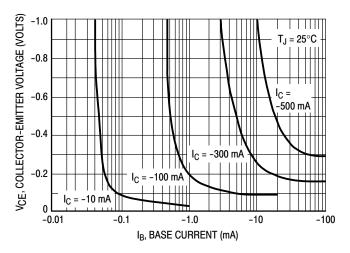


Figure 13. Saturation Region

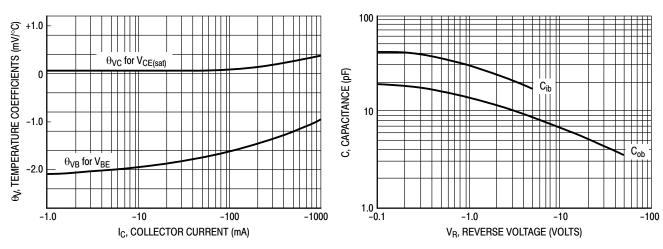


Figure 14. Temperature Coefficients

Figure 15. Capacitances

TYPICAL CHARACTERISTICS - BC807-40LT1

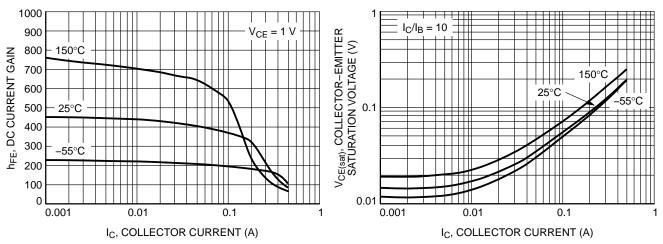


Figure 16. DC Current Gain vs. Collector Current

Figure 17. Collector Emitter Saturation Voltage vs. Collector Current

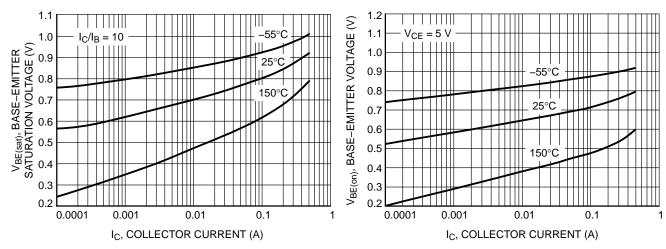


Figure 18. Base Emitter Saturation Voltage vs.
Collector Current

Figure 19. Base Emitter Voltage vs. Collector
Current

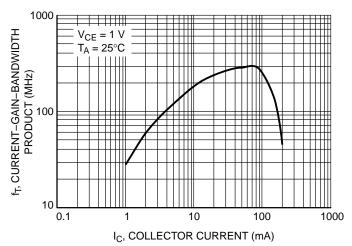


Figure 20. Current Gain Bandwidth Product vs. Collector Current

TYPICAL CHARACTERISTICS - BC807-40LT1

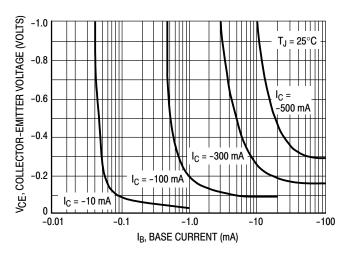


Figure 21. Saturation Region

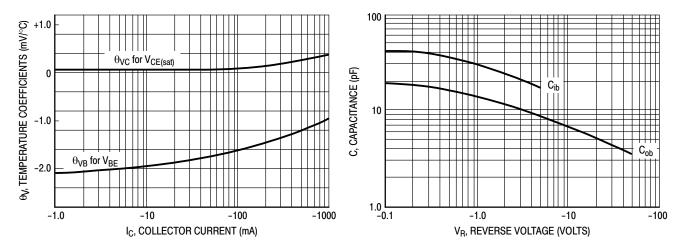


Figure 22. Temperature Coefficients

Figure 23. Capacitances

TYPICAL CHARACTERISTICS - BC807-16LT1, BC807-25LT1, BC807-40LT1

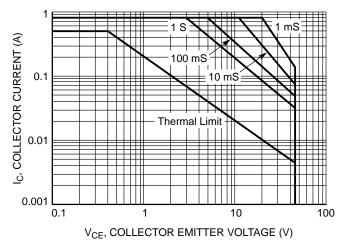
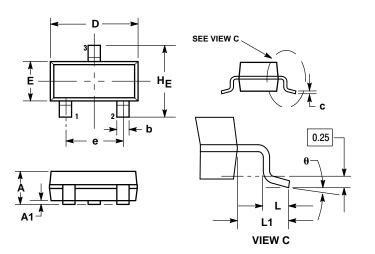


Figure 24. Safe Operating Area

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AP**



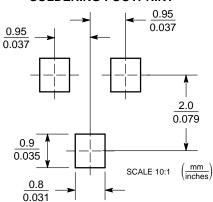
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH,
- PROTRUSIONS, OR GATE BURRS

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104
θ	0°		10°	0°		10°

STYLE 6: PIN 1. BASE

EMITTER 2. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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